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(71) Applicant: **HONEYWELL INTERNATIONAL INC.**
[US/US]; Law Dept. AB2, 101 Columbia Road, P.O. Box
2245, Morristown, NJ 07962 (US).

(72) Inventors: **GUO, Wei**; 537 Ten Point Lane, Cranberry
Twp., PA 16066 (US). **TURNER, Stephen, P.**; 4026 Turn-
wood Lane, Moon, PA 15108 (US). **CAWLEY, Edward,**
F.; 102 Staghorn Drive, Sewickley, PA 15143 (US).

(74) Agent: **LATWESEN, David, G.**; Wells St. John P.S., 601
West First Ave., #1300, Spokane, WA 99201 (US).

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(54) Title: HIGH PURITY NICKEL/VANADIUM SPUTTERING COMPONENTS; AND METHODS OF MAKING SPUTTER-
ING COMPONENTS

(57) Abstract: The invention includes sputtering components, such as sputtering targets, comprising high-purity Ni-V. The sputter-
ing components can have a fine average grain size throughout, with an exemplary fine average grain size being a grain size less than
or equal to 40 microns. The invention also includes methods of making high-purity Ni-V structures.



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